

BLC10G18XS-552AVT

Power LDMOS transistor

Rev. 1 — 31 October 2019

AMPLEON

Product data sheet

1. Product profile

1.1 General description

550 W LDMOS packaged asymmetric Doherty power transistor for base station applications at frequencies from 1805 MHz to 1880 MHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25\text{ °C}$ in an asymmetrical Doherty demo circuit. $V_{DS} = 30\text{ V}$; $I_{DQ} = 950\text{ mA}$ (main); $V_{GS(amp)peak} = 1.1\text{ V}$, unless otherwise specified.

| Test signal | f | V_{DS} | $P_{L(AV)}$ | G_p | η_D | ACPR |
|------------------|--------------|----------|-------------|-------|----------|---------------------------|
| | (MHz) | (V) | (dBm) | (dB) | (%) | (dBc) |
| 1-carrier W-CDMA | 1805 to 1880 | 30 | 49.5 | 16.8 | 48.3 | -32.1 [1] |

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

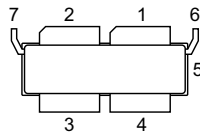
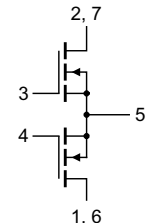
- Excellent ruggedness
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1880 MHz frequency range

2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|-----|-------------------------|--|---|
| 1 | drain2 (peak) |  |  aaa-014884 |
| 2 | drain1 (main) | | |
| 3 | gate1 (main) | | |
| 4 | gate2 (peak) | | |
| 5 | source ^[1] | | |
| 6 | video decoupling (peak) | | |
| 7 | video decoupling (main) | | |

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------------|---------|---|-----------|
| | Name | Description | Version |
| BLC10G18XS-552AVT | - | air cavity plastic earless flanged package; 6 leads | SOT1258-4 |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|------------------------------------|--------------------------|-----|------|------|
| V_{DS} | drain-source voltage | | - | 65 | V |
| $V_{GS(amp)main}$ | main amplifier gate-source voltage | | -6 | +9 | V |
| $V_{GS(amp)peak}$ | peak amplifier gate-source voltage | | -6 | +9 | V |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | ^[1] | - | 225 | °C |
| T_{case} | case temperature | operating ^[1] | -40 | +125 | °C |

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Typ | Unit |
|---------------|--|--|------|------|
| $R_{th(j-c)}$ | thermal resistance from junction to case | $V_{DS} = 30$ V; $I_{Dq} = 950$ mA (main); $V_{GS(amp)peak} = 1.03$ V; $T_{case} = 80$ °C | | |
| | | $P_L = 115$ W | 0.21 | k/W |
| | | $P_L = 145$ W | 0.19 | k/W |

6. Characteristics

Table 6. DC characteristics

$T_j = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------|----------------------------------|---|-----|------|-----|------------------|
| Main device | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $V_{GS} = 0\text{ V}; I_D = 1.8\text{ mA}$ | 65 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $V_{DS} = 10\text{ V}; I_D = 180\text{ mA}$ | 1.6 | 2.0 | 2.4 | V |
| V_{GSq} | gate-source quiescent voltage | $V_{DS} = 30\text{ V}; I_D = 950\text{ mA}$ | - | 2.1 | - | V |
| I_{DSS} | drain leakage current | $V_{GS} = 0\text{ V}; V_{DS} = 30\text{ V}$ | - | - | 2.8 | μA |
| I_{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 2.37\text{ V}; V_{DS} = 10\text{ V}$ | - | 34 | - | A |
| I_{GSS} | gate leakage current | $V_{GS} = 9\text{ V}; V_{DS} = 0\text{ V}$ | - | - | 280 | nA |
| g_{fs} | forward transconductance | $V_{DS} = 10\text{ V}; I_D = 9.0\text{ A}$ | - | 20.5 | - | S |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 2.37\text{ V}; I_D = 6.3\text{ A}$ | - | 72 | 108 | $\text{m}\Omega$ |
| Peak device | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $V_{GS} = 0\text{ V}; I_D = 3.8\text{ mA}$ | 65 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $V_{DS} = 10\text{ V}; I_D = 380\text{ mA}$ | 1.6 | 2.0 | 2.4 | V |
| V_{GSq} | gate-source quiescent voltage | $V_{DS} = 30\text{ V}; I_D = 1900\text{ mA}$ | - | 2.1 | - | V |
| I_{DSS} | drain leakage current | $V_{GS} = 0\text{ V}; V_{DS} = 30\text{ V}$ | - | - | 2.8 | μA |
| I_{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 2.37\text{ V}; V_{DS} = 10\text{ V}$ | - | 57 | - | A |
| I_{GSS} | gate leakage current | $V_{GS} = 9\text{ V}; V_{DS} = 0\text{ V}$ | - | - | 280 | nA |
| g_{fs} | forward transconductance | $V_{DS} = 10\text{ V}; I_D = 19.0\text{ A}$ | - | 39 | - | S |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 2.37\text{ V}; I_D = 13.3\text{ A}$ | - | 37 | 62 | $\text{m}\Omega$ |

Table 7. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 DPCH; $f_1 = 1807.5\text{ MHz}$; $f_2 = 1877.5\text{ MHz}$; RF performance at $V_{DS} = 30\text{ V}$; $I_{Dq} = 950\text{ mA}$ (main); $V_{GS(amp)peak} = 1.13\text{ V}$; $T_{case} = 25\text{ }^{\circ}\text{C}$; unless otherwise specified; in an asymmetrical Doherty production test circuit at frequencies from 1805 MHz to 1880 MHz.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|------------------------------|----------------------------|------|------|-----|------|
| G_p | power gain | $P_{L(AV)} = 115\text{ W}$ | 15.1 | 16.1 | - | dB |
| RL_{in} | input return loss | $P_{L(AV)} = 115\text{ W}$ | - | -13 | -8 | dB |
| η_D | drain efficiency | $P_{L(AV)} = 115\text{ W}$ | 44 | 48 | - | % |
| ACPR | adjacent channel power ratio | $P_{L(AV)} = 115\text{ W}$ | - | -33 | -28 | dBc |

Table 8. RF characteristics

Test signal: 1-carrier W-CDMA; PAR = 9.6 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 64 DPCH; $f = 1877.5\text{ MHz}$; RF performance at $V_{DS} = 30\text{ V}$; $I_{Dq} = 950\text{ mA}$ (main); $V_{GS(amp)peak} = 1.13\text{ V}$; $T_{case} = 25\text{ }^{\circ}\text{C}$; unless otherwise specified; in an asymmetrical Doherty production test circuit at a frequency of 1880 MHz.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------|------------------------------|----------------------------|-----|-----|-----|------|
| PAR_O | output peak-to-average ratio | $P_{L(AV)} = 148\text{ W}$ | 6.3 | 6.8 | - | dB |
| $P_{L(M)}$ | peak output power | $P_{L(AV)} = 148\text{ W}$ | 620 | 705 | - | W |

7. Test information

7.1 Ruggedness in Doherty operation

The BLC10G18XS-552AVT is capable of withstanding a load mismatch corresponding to $V_{SWR} = 10 : 1$ through all phases under the following conditions: $V_{DS} = 30$ V; $I_{DQ} = 800$ mA; $V_{GS(amp)peak} = 1.15$ V; $f = 1805$ MHz; $P_L = 235$ W (5 dB OBO); 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.6 dB at 0.01 % probability on CCDF.

7.2 Impedance information

Table 9. Typical impedance of main device

Measured load-pull data of main device; $I_{DQ} = 1$ A (main); $V_{DS} = 30$ V; pulsed CW ($t_p = 100$ μ s; $\delta = 10$ %).

| f | Z _S [1] | Z _L [1] | P _L [2] | η_D [2] | G _p [2] |
|--------------------------------------|--------------------|--------------------|--------------------|--------------|--------------------|
| (MHz) | (Ω) | (Ω) | (W) | (%) | (dB) |
| Maximum power load | | | | | |
| 1810 | 2.6 – j6.6 | 1.8 – j3.1 | 285.36 | 61.99 | 16.39 |
| 1845 | 3.5 – j7.3 | 1.5 – j3.1 | 286.73 | 59.31 | 16.25 |
| 1880 | 4.6 – j7.8 | 1.6 – j3.2 | 281.16 | 60.32 | 16.41 |
| Maximum drain efficiency load | | | | | |
| 1810 | 2.6 – j6.6 | 3.2 – j2.2 | 203.39 | 68.8 | 18.26 |
| 1845 | 3.5 – j7.3 | 3.0 – j1.5 | 180.88 | 68.43 | 18.81 |
| 1880 | 4.6 – j7.8 | 2.7 – j2.0 | 199.61 | 68.01 | 18.48 |

[1] Z_S and Z_L defined in [Figure 1](#).

[2] At 3 dB gain compression.

Table 10. Typical impedance of peak device

Measured load-pull data of peak device; $I_{DQ} = 1.9$ A (peak); $V_{DS} = 30$ V; pulsed CW ($t_p = 100$ μ s; $\delta = 10$ %).

| f | Z _S [1] | Z _L [1] | P _L [2] | η_D [2] | G _p [2] |
|--------------------------------------|--------------------|--------------------|--------------------|--------------|--------------------|
| (MHz) | (Ω) | (Ω) | (W) | (%) | (dB) |
| Maximum power load | | | | | |
| 1810 | 2.2 – j4.5 | 1.5 – j2.9 | 550.81 | 59.45 | 16.7 |
| 1845 | 3.3 – j4.0 | 1.5 – j2.9 | 541 | 59.25 | 17.05 |
| 1880 | 4.0 – j3.5 | 1.6 – j2.8 | 529.9 | 60.76 | 17.6 |
| Maximum drain efficiency load | | | | | |
| 1810 | 2.2 – j4.5 | 2.1 – j1.6 | 393.5 | 67.11 | 18.76 |
| 1845 | 3.3 – j4.0 | 1.5 – j1.6 | 366.31 | 65.83 | 19.35 |
| 1880 | 4.0 – j3.5 | 1.5 – j1.7 | 372.09 | 65.86 | 19.54 |

[1] Z_S and Z_L defined in [Figure 1](#).

[2] At 3 dB gain compression.

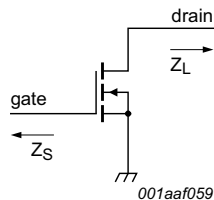
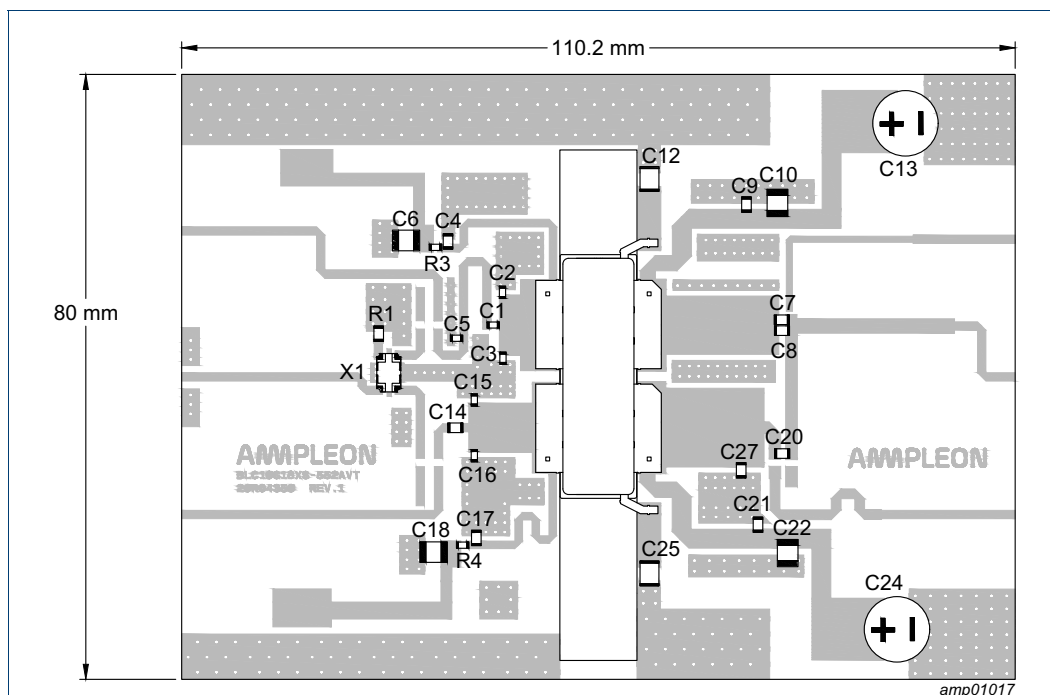


Fig 1. Definition of transistor impedance

7.3 Test circuit



Printed-Circuit Board (PCB): Rogers RO4350B; $\epsilon_r = 3.5$; thickness = 0.508 mm; thickness copper plating = 35 μm .

See [Table 11](#) for a list of components.

Fig 2. Component layout

Table 11. List of components

See [Figure 2](#) for component layout.

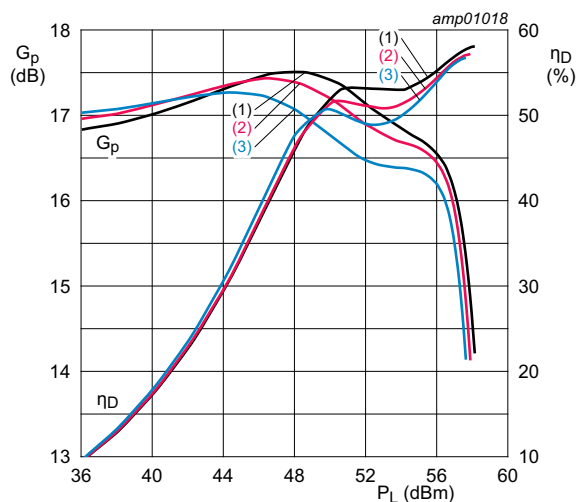
| Component | Description | Value | Remarks |
|-----------------------------|-----------------------------------|--------------------------|-------------|
| C1 | multilayer ceramic chip capacitor | 1.8 pF | GQM18 |
| C2, C3 | multilayer ceramic chip capacitor | 1.0 pF | GQM18 |
| C4, C9, C14, C17, C21 | multilayer ceramic chip capacitor | 18 pF | GQM21 |
| C5 | multilayer ceramic chip capacitor | 1.8 pF | GQM21 |
| C6, C10, C12, C18, C22, C25 | electrolytic capacitor | 4.7 μF , 50 V | Murata: X7R |
| C7, C8 | multilayer ceramic chip capacitor | 8.2 pF | GQM21 |
| C11, C19, C23, C26 | multilayer ceramic chip capacitor | | not mounted |

Table 11. List of components ...continued
See [Figure 2](#) for component layout.

| Component | Description | Value | Remarks |
|-----------|-----------------------------------|-------------------|---------------------|
| C13, C24 | multilayer ceramic chip capacitor | 470 μ F, 63 V | Elco |
| C15, C16 | multilayer ceramic chip capacitor | 1.8 pF | GQM21 |
| C20 | multilayer ceramic chip capacitor | 10 pF | GQM21 |
| C27 | multilayer ceramic chip capacitor | 0.4 pF | GQM21 |
| R1 | resistor | 50 Ω | Anaren: C16A50Z4 |
| R2 | resistor | | not mounted |
| R3, R4 | resistor | 5.1 Ω | |
| X1 | hybrid coupler | | Anaren: X3C20F1-02S |

7.4 Graphical data

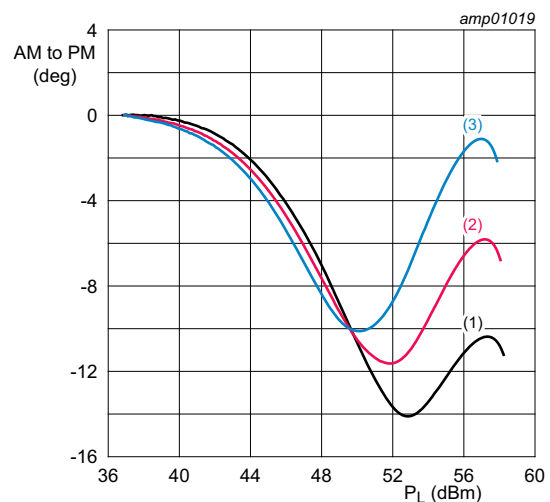
7.4.1 Pulsed CW



$V_{DS} = 30$ V; $I_{DQ} = 950$ mA; $V_{GS(amp)peak} = 1.10$ V;
 $t_p = 100$ μ s; $\delta = 10$ %.

- (1) $f = 1805$ MHz
- (2) $f = 1845$ MHz
- (3) $f = 1880$ MHz

Fig 3. Power gain and drain efficiency as function of output power; typical values



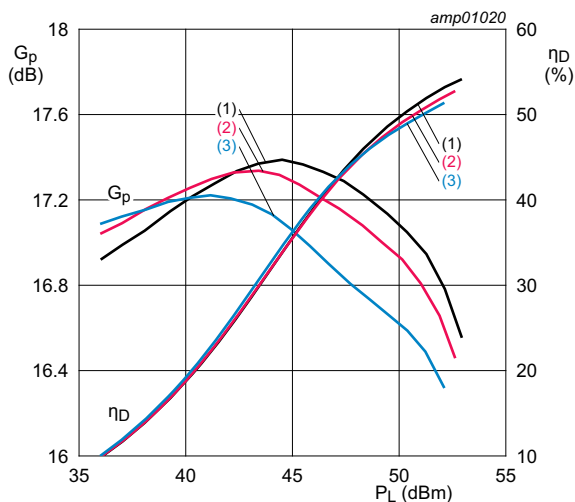
$V_{DS} = 30$ V; $I_{DQ} = 950$ mA; $V_{GS(amp)peak} = 1.10$ V;
 $t_p = 100$ μ s; $\delta = 10$ %.

- (1) $f = 1805$ MHz
- (2) $f = 1845$ MHz
- (3) $f = 1880$ MHz

Fig 4. Normalized AM to PM as a function of output power; typical values

7.4.2 1-Carrier W-CDMA

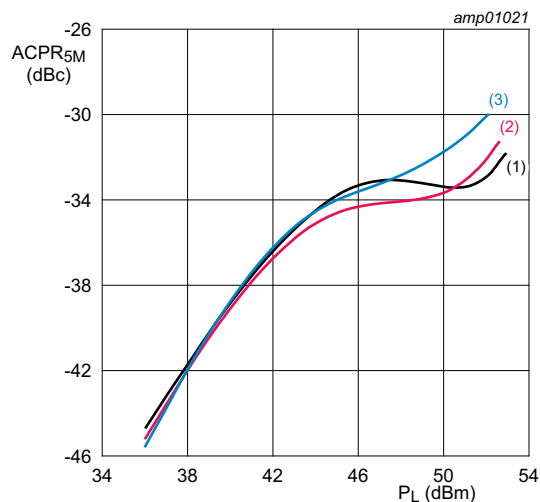
Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.9 dB at 0.01 % probability on CCDF.



$V_{DS} = 30\text{ V}$; $I_{Dq} = 950\text{ mA}$; $V_{GS(amp)peak} = 1.10\text{ V}$.

- (1) $f = 1805\text{ MHz}$
- (2) $f = 1845\text{ MHz}$
- (3) $f = 1880\text{ MHz}$

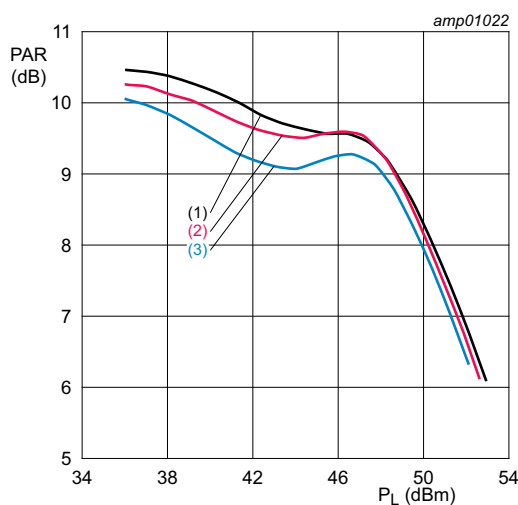
Fig 5. Power gain and drain efficiency as function of output power; typical values



$V_{DS} = 30\text{ V}$; $I_{Dq} = 950\text{ mA}$; $V_{GS(amp)peak} = 1.10\text{ V}$.

- (1) $f = 1805\text{ MHz}$
- (2) $f = 1845\text{ MHz}$
- (3) $f = 1880\text{ MHz}$

Fig 6. Adjacent channel power ratio (5 MHz) as a function of output power; typical values

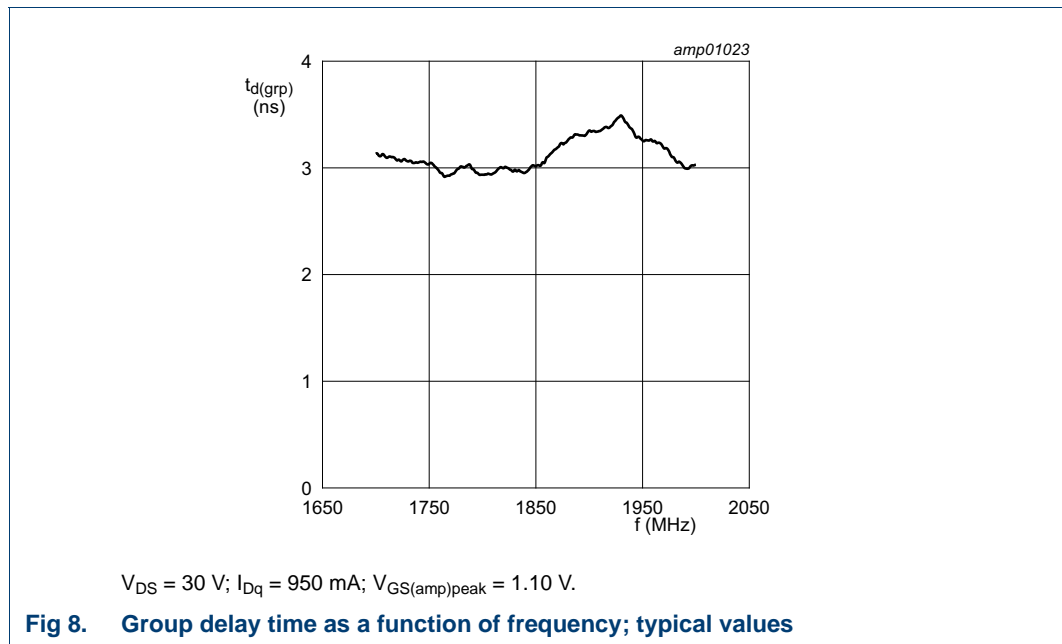


$V_{DS} = 30\text{ V}$; $I_{Dq} = 950\text{ mA}$; $V_{GS(amp)peak} = 1.10\text{ V}$.

- (1) $f = 1805\text{ MHz}$
- (2) $f = 1845\text{ MHz}$
- (3) $f = 1880\text{ MHz}$

Fig 7. Peak-to-average power ratio as a function of output power; typical values

7.4.3 Group delay



8. Package outline

Air cavity plastic earless flanged package; 6 leads

SOT1258-4

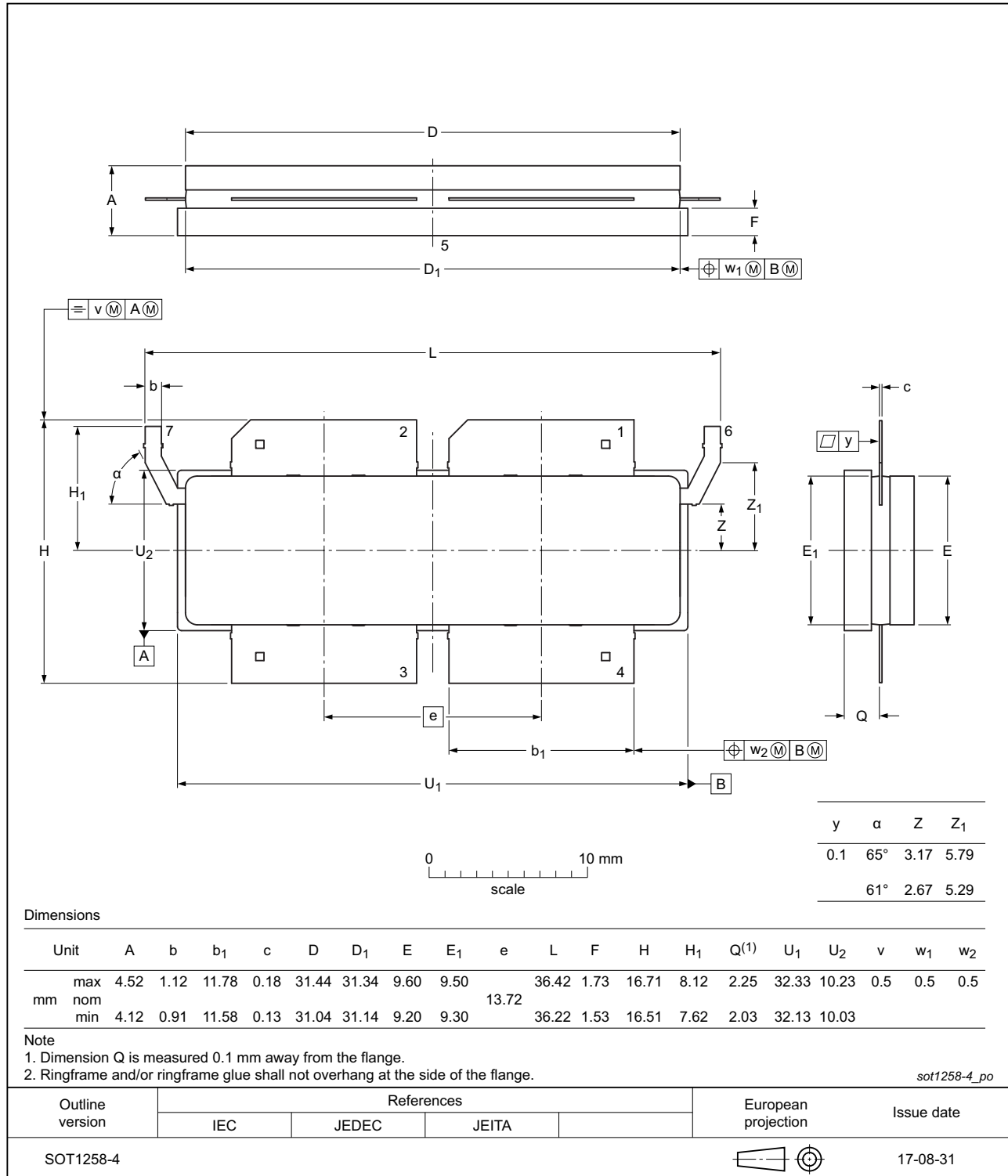


Fig 9. Package outline SOT1258-4

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

Table 12. ESD sensitivity

| ESD model | Class |
|--|------------------------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C3 [1] |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001 | 2 [2] |

[1] CDM classification C3 is granted to any part that passes after exposure to an ESD pulse of 1000 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

Table 13. Abbreviations

| Acronym | Description |
|---------|--|
| 3GPP | 3rd Generation Partnership Project |
| AM | Amplitude Modulation |
| CCDF | Complementary Cumulative Distribution Function |
| CW | Continuous Wave |
| DPCH | Dedicated Physical CHannel |
| ESD | ElectroStatic Discharge |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor |
| MTF | Median Time to Failure |
| OBO | Output Back Off |
| PAR | Peak-to-Average Ratio |
| PM | Phase Modulation |
| RoHS | Restriction of Hazardous Substances |
| VSWR | Voltage Standing Wave Ratio |
| W-CDMA | Wideband Code Division Multiple Access |

11. Revision history

Table 14. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------------|--------------|--------------------|---------------|------------|
| BLC10G18XS-552AVT v.1 | 20191031 | Product data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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For sales office addresses, please visit: <http://www.ampleon.com/sales>

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